







Texas INSTRUMENTS

SN74HCS00-Q1 SCLS758D - JULY 2019 - REVISED DECEMBER 2021

# SN74HCS00-Q1 Automotive Quadruple 2-Input NAND Gates with Schmitt-Trigger Inputs

## 1 Features

- AEC-Q100 qualified for automotive applications: - Device temperature grade 1:
  - -40°C to +125°C, T<sub>A</sub>
  - Device HBM ESD Classification Level 2 Device CDM ESD Classification Level C6
- Available in wettable flank QFN (WRKS) package
- Wide operating voltage range: 2 V to 6 V •
- Schmitt-trigger inputs allow for slow or noisy input • signals
- Low power consumption
  - Typical I<sub>CC</sub> of 100 nA
  - Typical input leakage current of ±100 nA
- ±7.8-mA output drive at 6 V ٠

## 2 Applications

- Alarm or tamper detect circuit
- S-R latch

## **3 Description**

This device contains four independent 2-input NAND Gates with Schmitt-trigger inputs. Each gate performs the Boolean function  $Y = \overline{A \bullet B}$  in positive logic.

| Device Information                                 |             |                   |  |  |  |  |  |
|--|-------------|-------------------|--|--|--|--|--|
| PART NUMBER PACKAGE <sup>(1)</sup> BODY SIZE (NOM) |             |                   |  |  |  |  |  |
| SN74HCS00PW-Q1                                     | TSSOP (14)  | 5.00 mm × 4.40 mm |  |  |  |  |  |
| SN74HCS00D-Q1                                      | SOIC (14)   | 8.70 mm × 3.90 mm |  |  |  |  |  |
| SN74HCS00BQA-Q1                                    | WQFN (14)   | 3.00 mm × 2.50 mm |  |  |  |  |  |
| SN74HCS00DYY-Q1                                    | SOT-23 (14) | 4.20 mm × 2.00 mm |  |  |  |  |  |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

|  | Low Power                                  | Noise Rejection           | Supports Slow Inputs      |
|--|--|---------------------------|---------------------------|
| Input Voltage<br>Waveforms                             | Debuto<br>Input Voltage                    | time                      | and<br>tindu<br>Time      |
| Standard<br>CMOS Input<br>Response<br>Waveforms        | Supply Current<br>Input Voltage            | Output<br>Current Voltage | Output<br>Lime            |
| Schmitt-trigger<br>CMOS Input<br>Response<br>Waveforms | Current<br>Subply Current<br>Input Voltage | Output<br>Outrent Voltage | Output<br>Current Voltage |

## **Benefits of Schmitt-Trigger Inputs**





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## **4 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| С | hanges from Revision C (March 2021) to Revision D (December 2021)  | Page |
|---|--|------|
| • | Added DYY package to the Device Information table  | 1    |
| • | Added DYY package information to the Pin Configuration and Functions section                                     |      |
| c | hanges from Revision B (September 2019) to Revision C (March 2021)   | Page |
| • | Updated the numbering format for tables, figures, and cross-references throughout the document                   | 1    |
| • | Added BQA package to Device Information table  | 1    |
| • | Added BQA package information to Pin Configuration and Functions   | 3    |
| • | Added DYY package information to Thermal Information table   |      |
| • | Added BQA package information to <i>Thermal Information</i> table  | 5    |
| С | hanges from Revision A (August 2019) to Revision B (September 2019)  | Page |
| • | Added D package to Device Information table  | 1    |
| • | Added D package column to Thermal Information table  |      |
| С | hanges from Revision * (July 2019) to Revision A (August 2019)   | Page |
| • | Fixed errors in the Pin Function Table   | 3    |
| • | Deleted "I <sub>CC</sub> " and "output" from "Continuous current through V <sub>CC</sub> or GND" row for clarity | 4    |



## **5** Pin Configuration and Functions



14-Pin SOIC, SOT-23, or TSSOP Top View



#### Table 5-1. Pin Functions

| PIN                      |     | I/O    | DESCRIPTION  |  |  |  |  |
|--------------------------|-----|--------|--|--|--|--|--|
| NAME                     | NO. | 1/0    | DESCRIPTION  |  |  |  |  |
| 1A                       | 1   | Input  | Channel 1, Input A   |  |  |  |  |
| 1B                       | 2   | Input  | Channel 1, Input B   |  |  |  |  |
| 1Y                       | 3   | Output | Channel 1, Output Y  |  |  |  |  |
| 2A                       | 4   | Input  | Channel 2, Input A   |  |  |  |  |
| 2B                       | 5   | Input  | Channel 2, Input B   |  |  |  |  |
| 2Y                       | 6   | Output | Channel 2, Output Y  |  |  |  |  |
| GND                      | 7   | —      | Ground   |  |  |  |  |
| 3Y                       | 8   | Output | Channel 3, Output Y  |  |  |  |  |
| 3A                       | 9   | Input  | Channel 3, Input A   |  |  |  |  |
| 3B                       | 10  | Input  | Channel 3, Input B   |  |  |  |  |
| 4Y                       | 11  | Output | Channel 4, Output Y  |  |  |  |  |
| 4A                       | 12  | Input  | Channel 4, Input A   |  |  |  |  |
| 4B                       | 13  | Input  | Channel 4, Input B   |  |  |  |  |
| V <sub>CC</sub>          | 14  | —      | Positive Supply  |  |  |  |  |
| Thermal Pad <sup>(</sup> | 1)  | _      | The thermal pad can be connected to GND or left floating. Do not connect to any other signal or supply |  |  |  |  |

(1) BQA Package only.

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|                  |                                       |  | MIN  | MAX | UNIT |
|------------------|---------------------------------------|--|------|-----|------|
| V <sub>CC</sub>  | Supply voltage                        |  | -0.5 | 7   | V    |
| I <sub>IK</sub>  | Input clamp current <sup>(2)</sup>    | $V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V |      | ±20 | mA   |
| Ι <sub>οκ</sub>  | Output clamp current <sup>(2)</sup>   | $V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V |      | ±20 | mA   |
| I <sub>O</sub>   | Continuous output current             | $V_{O} = 0$ to $V_{CC}$                                    |      | ±35 | mA   |
|                  | Continuous current through $V_{CC}$ o | r GND  |      | ±70 | mA   |
| TJ               | Junction temperature <sup>(3)</sup>   |  |      | 150 | °C   |
| T <sub>stg</sub> | Storage temperature                   |  | -65  | 150 | °C   |

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute maximum ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If briefly operating outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) Assured by design.

### 6.2 ESD Ratings

|                     |                         |   | VALUE | UNIT |
|---------------------|-------------------------|---|-------|------|
| V Electrostatic dis | Electrostatic discharge | Human body model (HBM), per AEC Q100-002 <sup>(1)</sup><br>HBM ESD Classification Level 2 |       | V    |
| V <sub>(ESD)</sub>  |                         | Charged device model (CDM), per AEC Q100-011 CDM ESD Classification Level C6              | ±1500 |      |

(1) AEC Q100-002 indicate that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

## 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                 |                                     | MIN | NOM | MAX             | UNIT |
|-----------------|-------------------------------------|-----|-----|-----------------|------|
| V <sub>CC</sub> | Supply voltage                      | 2   | 5   | 6               | V    |
| VI              | Input voltage                       | 0   |     | V <sub>CC</sub> | V    |
| Vo              | Output voltage                      | 0   |     | V <sub>CC</sub> | V    |
| Δt/Δv           | Input transition rise and fall rate |     |     | Unlimited       | ns/V |
| T <sub>A</sub>  | Ambient temperature                 | -40 |     | 125             | °C   |



### 6.4 Thermal Information

|                       | THERMAL METRIC <sup>(1)</sup>                | DYY (SOT) | PW (TSSOP) | D (SOIC) | BQA (WQFN) | UNIT |
|-----------------------|--|-----------|------------|----------|------------|------|
|                       |  | 14 PINS   | 14 PINS    | 14 PINS  | 14 PINS    |      |
| R <sub>θJA</sub>      | Junction-to-ambient thermal resistance       | 236.5     | 151.7      | 133.6    | 109.7      | °C/W |
| R <sub>0JC(top)</sub> | Junction-to-case (top) thermal resistance    | 143.2     | 79.4       | 89.0     | 111.0      | °C/W |
| $R_{\theta J B}$      | Junction-to-board thermal resistance         | 146       | 94.7       | 89.5     | 77.9       | °C/W |
| $\Psi_{JT}$           | Junction-to-top characterization parameter   | 29.5      | 25.2       | 45.5     | 20.2       | °C/W |
| $\Psi_{JB}$           | Junction-to-board characterization parameter | 145.6     | 94.1       | 89.1     | 77.8       | °C/W |
| R <sub>0JC(bot)</sub> | Junction-to-case (bottom) thermal resistance | N/A       | N/A        | N/A      | 56.6       | °C/W |

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

## **6.5 Electrical Characteristics**

over operating free-air temperature range; typical ratings measured at  $T_A = 25^{\circ}C$  (unless otherwise noted).

|                 | PARAMETER                                       | TEST CC                               | NDITIONS                  | V <sub>cc</sub> | MIN                   | ТҮР                     | MAX   | UNIT |
|-----------------|---|---------------------------------------|---------------------------|-----------------|-----------------------|-------------------------|-------|------|
|                 |   |                                       |                           | 2 V             | 0.7                   |                         | 1.5   |      |
| $V_{T+}$        | Positive switching threshold                    |                                       |                           | 4.5 V           | 1.7                   |                         | 3.15  | V    |
|                 |   |                                       |                           | 6 V             | 2.1                   |                         | 4.2   |      |
|                 |   |                                       |                           | 2 V             | 0.3                   |                         | 1.0   |      |
| V <sub>T-</sub> | Negative switching threshold                    |                                       |                           | 4.5 V           | 0.9                   |                         | 2.2   | V    |
|                 |   |                                       |                           | 6 V             | 1.2                   |                         | 3.0   |      |
|                 |   |                                       |                           | 2 V             | 0.2                   |                         | 1.0   |      |
| $\Delta V_T$    | Hysteresis (V <sub>T+</sub> - V <sub>T-</sub> ) |                                       |                           | 4.5 V           | 0.4                   |                         | 1.4   | V    |
|                 |   |                                       |                           | 6 V             | 0.6                   |                         | 1.6   | 3    |
|                 |   |                                       | I <sub>OH</sub> = -20 μA  | 2 V to 6 V      | V <sub>CC</sub> – 0.1 | V <sub>CC</sub> - 0.002 |       |      |
| V <sub>OH</sub> | High-level output voltage                       | $V_{I} = V_{IH} \text{ or } V_{IL}$   | I <sub>OH</sub> = -6 mA   | 4.5 V           | 4.0                   | 4.3                     |       | V    |
|                 |   |                                       | I <sub>OH</sub> = -7.8 mA | 6 V             | 5.4                   | 5.75                    |       |      |
|                 |   |                                       | I <sub>OL</sub> = 20 μA   | 2 V to 6 V      |                       | 0.002                   | 0.1   |      |
| V <sub>OL</sub> | Low-level output voltage                        | $V_{I} = V_{IH} \text{ or } V_{IL}$   | I <sub>OL</sub> = 6 mA    | 4.5 V           |                       | 0.18                    | 0.30  | V    |
|                 |   |                                       | I <sub>OL</sub> = 7.8 mA  | 6 V             |                       | 0.22                    | 0.33  |      |
| I <sub>I</sub>  | Input leakage current                           | $V_{I} = V_{CC} \text{ or } 0$        |                           | 6 V             |                       | ±100                    | ±1000 | nA   |
| I <sub>CC</sub> | Supply current                                  | $V_{I} = V_{CC} \text{ or } 0, I_{C}$ | <sub>D</sub> = 0          | 6 V             |                       | 0.1                     | 2     | μA   |
| Ci              | Input capacitance                               |                                       |                           | 2 V to 6 V      |                       |                         | 5     | pF   |
| C <sub>pd</sub> | Power dissipation capacitance per gate          | No load                               |                           | 2 V to 6 V      |                       | 10                      |       | pF   |



## 6.6 Switching Characteristics

 $C_L$  = 50 pF; over operating free-air temperature range; typical values measured at  $T_A$  = 25°C (unless otherwise noted). See *Parameter Measurement Information* 

| PARAMETER       |                   | FROM (INPUT) | TO (OUTPUT) | V <sub>cc</sub> | MIN | ТҮР | MAX | UNIT |
|-----------------|-------------------|--------------|-------------|-----------------|-----|-----|-----|------|
| t <sub>pd</sub> | Propagation delay |              |             | 2 V             |     | 15  | 36  |      |
|                 |                   | A or B       |             | 4.5 V           |     | 7   | 13  | ns   |
|                 |                   |              |             | 6 V             |     | 5   | 12  |      |
|                 | Transition-time   |              | Y           | 2 V             |     | 9   | 16  |      |
| tt              |                   |              |             | 4.5 V           |     | 5   | 9   | ns   |
|                 |                   |              |             | 6 V             |     | 4   | 8   |      |

## 6.7 Typical Characteristics

T<sub>A</sub> = 25°C





## 7 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>t</sub> < 2.5 ns.

For clock inputs, f<sub>max</sub> is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.







(1) The greater between t<sub>PLH</sub> and t<sub>PHL</sub> is the same as t<sub>pd</sub>. Figure 7-2. Voltage Waveforms Propagation Delays



(1) The greater between  $t_r$  and  $t_f$  is the same as  $t_t$ .

Figure 7-3. Voltage Waveforms, Input and Output Transition Times



## 8 Detailed Description

## 8.1 Overview

This device contains four independent 2-input NAND Gates with Schmitt-trigger inputs. Each gate performs the Boolean function  $Y = \overline{A \bullet B}$  in positive logic.

### 8.2 Functional Block Diagram



### 8.3 Feature Description

### 8.3.1 Balanced CMOS Push-Pull Outputs

This device includes balanced CMOS push-pull outputs. The term *balanced* indicates that the device can sink and source similar currents. The drive capability of this device may create fast edges into light loads so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. It is important for the output power of the device to be limited to avoid damage due to overcurrent. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

Unused push-pull CMOS outputs should be left disconnected.

#### 8.3.2 CMOS Schmitt-Trigger Inputs

This device includes inputs with the Schmitt-trigger architecture. These inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics* table from the input to ground. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings* table, and the maximum input leakage current, given in the *Electrical Characteristics* table, using Ohm's law ( $R = V \div I$ ).

The Schmitt-trigger input architecture provides hysteresis as defined by  $\Delta V_T$  in the *Electrical Characteristics* table, which makes this device extremely tolerant to slow or noisy inputs. While the inputs can be driven much slower than standard CMOS inputs, it is still recommended to properly terminate unused inputs. Driving the inputs with slow transitioning signals will increase dynamic current consumption of the device. For additional information regarding Schmitt-trigger inputs, please see Understanding Schmitt Triggers.

#### 8.3.3 Clamp Diode Structure

The inputs and outputs to this device have both positive and negative clamping diodes as depicted in Figure 8-1.

#### CAUTION

Voltages beyond the values specified in the *Absolute Maximum Ratings* table can cause damage to the device. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.







#### 8.3.4 Wettable Flanks

This device includes wettable flanks for at least one package. See the *Features* section on the front page of the data sheet for which packages include this feature.



Figure 8-2. Simplified Cutaway View of Wettable-Flank QFN Package and Standard QFN Package After Soldering

Wettable flanks help improve side wetting after soldering which makes QFN packages easier to inspect with automatic optical inspection (AOI). A wettable flank can be dimpled or step-cut to provide additional surface area for solder adhesion which assists in reliably creating a side fillet as shown in Figure 8-2. Please see the mechanical drawing for additional details.

#### 8.4 Device Functional Modes

| INP | UTS | OUTPUT |  |  |  |
|-----|-----|--------|--|--|--|
| Α   | В   | Y      |  |  |  |
| Н   | Н   | L      |  |  |  |
| L   | Х   | Н      |  |  |  |
| Х   | L   | Н      |  |  |  |

#### Table 8-1. Function Table



## 9 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 9.1 Application Information

In this application, two 2-input NAND gates are used to create an active-low SR latch as shown in Figure 9-1. The two additional gates can be used for a second SR latch, or the inputs can be grounded and both channels left unused.

The SN74HCS00-Q1 is used to drive the tamper indicator LED and provide one bit of data to the system controller. When the tamper switch outputs LOW, the output Q becomes HIGH. This output remains HIGH until the system controller addresses the event and sends a LOW signal to the  $\overline{R}$  input which returns the Q output back to LOW.

The inputs of this active-low SR latch can often be driven by open-drain outputs which can produce slow input transition rates when they transition from LOW to Hi-Z. This makes the SN74HCS00-Q1 ideal for the application because it has Schmitt-trigger inputs that do not have input transition rate requirements.

#### 9.2 Typical Application



Figure 9-1. Typical Application Block Diagram

#### 9.2.1 Design Requirements

- All signals in the system operate at 5 V
- Avoid unstable state by not having LOW signals on both inputs
- Q output is HIGH when  $\overline{S}$  is LOW
  - Q output remains HIGH until  $\overline{R}$  is LOW

#### 9.2.1.1 Power Considerations

Ensure the desired supply voltage is within the range specified in the *Recommended Operating Conditions*. The supply voltage sets the device's electrical characteristics as described in the *Electrical Characteristics*.

The positive voltage supply must be capable of sourcing current equal to the total current to be sourced by all outputs of the SN74HCS00-Q1 plus the maximum static supply current,  $I_{CC}$ , listed in *Electrical Characteristics* and any transient current required for switching. The logic device can only source as much current as is provided by the positive supply source. Be sure not to exceed the maximum total current through  $V_{CC}$  listed in the *Absolute Maximum Ratings*.



The ground must be capable of sinking current equal to the total current to be sunk by all outputs of the SN74HCS00-Q1 plus the maximum supply current,  $I_{CC}$ , listed in *Electrical Characteristics*, and any transient current required for switching. The logic device can only sink as much current as can be sunk into its ground connection. Be sure not to exceed the maximum total current through GND listed in the *Absolute Maximum Ratings*.

The SN74HCS00-Q1 can drive a load with a total capacitance less than or equal to 50 pF while still meeting all of the data sheet specifications. Larger capacitive loads can be applied; however, it is not recommended to exceed 50 pF.

The SN74HCS00-Q1 can drive a load with total resistance described by  $R_L \ge V_O / I_O$ , with the output voltage and current defined in the *Electrical Characteristics* table with  $V_{OH}$  and  $V_{OL}$ . When outputting in the high state, the output voltage in the equation is defined as the difference between the measured output voltage and the supply voltage at the  $V_{CC}$  pin.

Total power consumption can be calculated using the information provided in CMOS Power Consumption and Cpd Calculation.

Thermal increase can be calculated using the information provided in Thermal Characteristics of Standard Linear and Logic (SLL) Packages and Devices.

#### CAUTION

The maximum junction temperature,  $T_{J(max)}$  listed in the *Absolute Maximum Ratings*, is an additional limitation to prevent damage to the device. Do not violate any values listed in the *Absolute Maximum Ratings*. These limits are provided to prevent damage to the device.

#### 9.2.1.2 Input Considerations

Input signals must cross  $V_{t-(min)}$  to be considered a logic LOW, and  $V_{t+(max)}$  to be considered a logic HIGH. Do not exceed the maximum input voltage range found in the *Absolute Maximum Ratings*.

Unused inputs must be terminated to either  $V_{CC}$  or ground. These can be directly terminated if the input is completely unused, or they can be connected with a pull-up or pull-down resistor if the input is to be used sometimes, but not always. A pull-up resistor is used for a default state of HIGH, and a pull-down resistor is used for a default state of LOW. The resistor size is limited by drive current of the controller, leakage current into the SN74HCS00-Q1, as specified in the *Electrical Characteristics*, and the desired input transition rate. A 10-k $\Omega$  resistor value is often used due to these factors.

The SN74HCS00-Q1 has no input signal transition rate requirements because it has Schmitt-trigger inputs.

Another benefit to having Schmitt-trigger inputs is the ability to reject noise. Noise with a large enough amplitude can still cause issues. To know how much noise is too much, please refer to the  $\Delta V_{T(min)}$  in the *Electrical Characteristics*. This hysteresis value will provide the peak-to-peak limit.

Unlike what happens with standard CMOS inputs, Schmitt-trigger inputs can be held at any valid value without causing huge increases in power consumption. The typical additional current caused by holding an input at a value other than  $V_{CC}$  or ground is plotted in the *Typical Characteristics*.

Refer to the *Feature Description* section for additional information regarding the inputs for this device.



#### 9.2.1.3 Output Considerations

The positive supply voltage is used to produce the output HIGH voltage. Drawing current from the output will decrease the output voltage as specified by the  $V_{OH}$  specification in the *Electrical Characteristics*. The ground voltage is used to produce the output LOW voltage. Sinking current into the output will increase the output voltage as specified by the  $V_{OL}$  specification in the *Electrical Characteristics*.

Push-pull outputs that could be in opposite states, even for a very short time period, should never be connected directly together. This can cause excessive current and damage to the device.

Two channels within the same device with the same input signals can be connected in parallel for additional output drive strength.

Unused outputs can be left floating. Do not connect outputs directly to V<sub>CC</sub> or ground.

Refer to Feature Description section for additional information regarding the outputs for this device.

#### 9.2.2 Detailed Design Procedure

- Add a decoupling capacitor from V<sub>CC</sub> to GND. The capacitor needs to be placed physically close to the device and electrically close to both the V<sub>CC</sub> and GND pins. An example layout is shown in the *Layout* section.
- Ensure the capacitive load at the output is ≤ 50 pF. This is not a hard limit, however it will ensure optimal performance. This can be accomplished by providing short, appropriately sized traces from the SN74HCS00-Q1 to one or more of the receiving devices.
- Ensure the resistive load at the output is larger than (V<sub>CC</sub> / I<sub>O(max)</sub>) Ω. This will ensure that the maximum output current from the *Absolute Maximum Ratings* is not violated. Most CMOS inputs have a resistive load measured in MΩ; much larger than the minimum calculated above.
- 4. Thermal issues are rarely a concern for logic gates; the power consumption and thermal increase, however, can be calculated using the steps provided in the application report, CMOS Power Consumption and Cpd Calculation.

#### 9.2.3 Application Curves



Figure 9-2. Application Timing Diagram

#### **10 Power Supply Recommendations**

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in the following layout example.



## 11 Layout

## **11.1 Layout Guidelines**

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or  $V_{CC}$ , whichever makes more sense for the logic function or is more convenient.

### 11.2 Layout Example



Figure 11-1. Example Layout for the SN74HCS00-Q1



## 12 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

### **12.1 Documentation Support**

#### 12.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, HCMOS Design Considerations application report
- Texas Instruments, CMOS Power Consumption and Cpd Calculation application report
- Texas Instruments, Designing With Logic application report

#### **12.2 Receiving Notification of Documentation Updates**

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### **12.3 Support Resources**

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 12.4 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 12.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



## PACKAGING INFORMATION

| Orderable Device | Status | Package Type | •       | Pins | •    | Eco Plan     | Lead finish/  | MSL Peak Temp      | Op Temp (°C) | Device Marking | Samples |
|------------------|--------|--------------|---------|------|------|--------------|---------------|--------------------|--------------|----------------|---------|
|                  | (1)    |              | Drawing |      | Qty  | (2)          | Ball material | (3)                |              | (4/5)          |         |
| SN74HCS00QBQARQ1 | ACTIVE | WQFN         | BQA     | 14   | 3000 | RoHS & Green | NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | HCS00Q         | Samples |
| SN74HCS00QDRQ1   | ACTIVE | SOIC         | D       | 14   | 2500 | RoHS & Green | NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | HCS00Q1        | Samples |
| SN74HCS00QDYYRQ1 | ACTIVE | SOT-23-THIN  | DYY     | 14   | 3000 | RoHS & Green | NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | HCS00Q         | Samples |
| SN74HCS00QPWRQ1  | ACTIVE | TSSOP        | PW      | 14   | 2000 | RoHS & Green | NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | HCS00Q         | Samples |

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF SN74HCS00-Q1 :

• Catalog : SN74HCS00

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product



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## TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| All dimensions are nominal |                 |                    |    |      |                          |                          |            |            |            |            |           |                  |
|----------------------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device                     | •               | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
| SN74HCS00QBQARQ1           | WQFN            | BQA                | 14 | 3000 | 180.0                    | 12.4                     | 2.8        | 3.3        | 1.1        | 4.0        | 12.0      | Q1               |
| SN74HCS00QDRQ1             | SOIC            | D                  | 14 | 2500 | 330.0                    | 16.4                     | 6.5        | 9.0        | 2.1        | 8.0        | 16.0      | Q1               |
| SN74HCS00QDYYRQ1           | SOT-23-<br>THIN | DYY                | 14 | 3000 | 330.0                    | 12.4                     | 4.8        | 3.6        | 1.6        | 8.0        | 12.0      | Q3               |
| SN74HCS00QPWRQ1            | TSSOP           | PW                 | 14 | 2000 | 330.0                    | 12.4                     | 6.9        | 5.6        | 1.6        | 8.0        | 12.0      | Q1               |



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# PACKAGE MATERIALS INFORMATION

3-Jun-2022



\*All dimensions are nominal

| Device           | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN74HCS00QBQARQ1 | WQFN         | BQA             | 14   | 3000 | 210.0       | 185.0      | 35.0        |
| SN74HCS00QDRQ1   | SOIC         | D               | 14   | 2500 | 356.0       | 356.0      | 35.0        |
| SN74HCS00QDYYRQ1 | SOT-23-THIN  | DYY             | 14   | 3000 | 336.6       | 336.6      | 31.8        |
| SN74HCS00QPWRQ1  | TSSOP        | PW              | 14   | 2000 | 356.0       | 356.0      | 35.0        |

# DYY0014A

# PACKAGE OUTLINE SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- 5. Reference JEDEC Registration MO-345, Variation AB



# **DYY0014A**

# EXAMPLE BOARD LAYOUT SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# **DYY0014A**

# **EXAMPLE STENCIL DESIGN** SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# **BQA 14**

2.5 x 3, 0.5 mm pitch

# **GENERIC PACKAGE VIEW**

## WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





# **BQA0014A**

# **PACKAGE OUTLINE**

## WQFN - 0.8 mm max height

PLASTIC QUAD FLAT PACK-NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



# **BQA0014A**

## **EXAMPLE BOARD LAYOUT**

## WQFN - 0.8 mm max height

PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



## **BQA0014A**

## **EXAMPLE STENCIL DESIGN**

## WQFN - 0.8 mm max height

PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



A. An integration of the information o

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



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